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# FDMA86151L

## Single N-Channel PowerTrench<sup>®</sup> MOSFET

100 V, 3.3 A, 88 mΩ

### Features

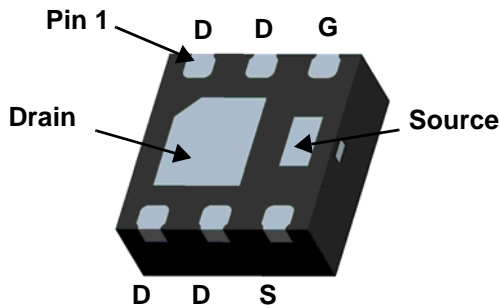
- Max  $r_{DS(on)}$  = 88 mΩ at  $V_{GS} = 10\text{ V}$ ,  $I_D = 3.3\text{ A}$
- Max  $r_{DS(on)}$  = 132 mΩ at  $V_{GS} = 4.5\text{ V}$ ,  $I_D = 2.7\text{ A}$
- Low Profile - 0.8 mm maximum in the new package MicroFET 2x2 mm
- Free from halogenated compounds and antimony oxides
- RoHS Compliant

### General Description

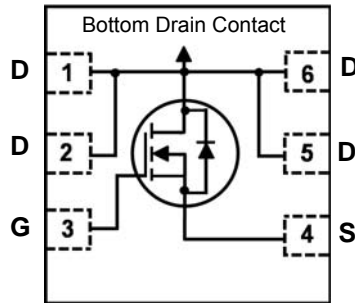
This device has been designed to provide maximum efficiency and thermal performance for synchronous buck converters. The low  $r_{DS(on)}$  and gate charge provide excellent switching performance.

### Application

- DC – DC Buck Converters



MicroFET 2X2 (Bottom View)



### MOSFET Maximum Ratings $T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Rated	Units
$V_{DS}$	Drain to Source Voltage	100	V
$V_{GS}$	Gate to Source Voltage	$\pm 20$	V
$I_D$	Drain Curre -Continuous $T_A = 25^\circ\text{C}$ (Note 1a)	3.3	A
	-Pulsed (Note 3)	20	
$P_D$	Power Dissipation $T_A = 25^\circ\text{C}$ (Note 1a)	2.4	W
	Power Dissipation $T_A = 25^\circ\text{C}$ (Note 1b)	0.9	
$T_J, T_{STG}$	Operating and Storage Junction Temperature Range	-55 to +150	$^\circ\text{C}$

### Thermal Characteristics

$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (Note 1a)	52	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (Note 1b)	145	

### Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
151	FDMA86151L	MicroFET 2X2	7"	8 mm	3000 units

## Electrical Characteristics $T_J = 25\text{ }^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
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### Off Characteristics

$BV_{DSS}$	Drain to Source Breakdown Voltage	$I_D = 250\ \mu\text{A}$ , $V_{GS} = 0\ \text{V}$	100			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250\ \mu\text{A}$ , referenced to $25\text{ }^\circ\text{C}$		69		$\text{mV}/^\circ\text{C}$
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{DS} = 80\ \text{V}$ , $V_{GS} = 0\ \text{V}$			1	$\mu\text{A}$
$I_{GSS}$	Gate to Source Leakage Current	$V_{GS} = \pm 20\ \text{V}$ , $V_{DS} = 0\ \text{V}$			100	nA

### On Characteristics

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}$ , $I_D = 250\ \mu\text{A}$	1.0	2.0	3.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250\ \mu\text{A}$ , referenced to $25\text{ }^\circ\text{C}$		-6		$\text{mV}/^\circ\text{C}$
$r_{DS(on)}$	Static Drain to Source On Resistance	$V_{GS} = 10\ \text{V}$ , $I_D = 3.3\ \text{A}$		60	88	m $\Omega$
		$V_{GS} = 4.5\ \text{V}$ , $I_D = 2.7\ \text{A}$		83	132	
		$V_{GS} = 10\ \text{V}$ , $I_D = 3.3\ \text{A}$ , $T_J = 125\text{ }^\circ\text{C}$		102	150	
$g_{FS}$	Forward Transconductance	$V_{DD} = 5\ \text{V}$ , $I_D = 3.3\ \text{A}$		8.6		S

### Dynamic Characteristics

$C_{iss}$	Input Capacitance	$V_{DS} = 50\ \text{V}$ , $V_{GS} = 0\ \text{V}$ , $f = 1\ \text{MHz}$		322	450	pF
$C_{oss}$	Output Capacitance			55	80	pF
$C_{riss}$	Reverse Transfer Capacitance			3	5	pF
$R_g$	Gate Resistance		0.1	1.9	3.8	$\Omega$

### Switching Characteristics

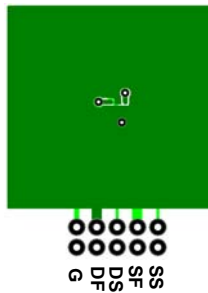
$t_{d(on)}$	Turn-On Delay Time	$V_{DD} = 50\ \text{V}$ , $I_D = 3.3\ \text{A}$ , $V_{GS} = 10\ \text{V}$ , $R_{GEN} = 6\ \Omega$		5.6	12	ns
$t_r$	Rise Time			1.4	10	ns
$t_{d(off)}$	Turn-Off Delay Time			11	20	ns
$t_f$	Fall Time			1.6	10	ns
$Q_{g(TOT)}$	Total Gate Charge	$V_{GS} = 0\ \text{V}$ to $10\ \text{V}$	$V_{DD} = 50\ \text{V}$ , $I_D = 3.3\ \text{A}$	5.2	7.3	nC
$Q_{g(TOT)}$	Total Gate Charge	$V_{GS} = 0\ \text{V}$ to $4.5\ \text{V}$		2.6	3.7	nC
$Q_{gs}$	Gate to Source Charge			1.1		nC
$Q_{gd}$	Gate to Drain "Miller" Charge			1.0		nC

### Drain-Source Diode Characteristics

$V_{SD}$	Source to Drain Diode Forward Voltage	$V_{GS} = 0\ \text{V}$ , $I_S = 3.3\ \text{A}$ (Note 2)		0.8	1.2	V
$t_{rr}$	Reverse Recovery Time	$I_F = 3.3\ \text{A}$ , $di/dt = 100\ \text{A}/\mu\text{s}$		33	53	ns
$Q_{rr}$	Reverse Recovery Charge			25	40	nC

#### NOTES:

1.  $R_{\theta JA}$  is determined with the device mounted on a  $1\ \text{in}^2$  pad 2 oz copper pad on a  $1.5 \times 1.5\ \text{in.}$  board of FR-4 material.  $R_{\theta JC}$  is guaranteed by design while  $R_{\theta JA}$  is determined by the user's board design.



a.  $52\text{ }^\circ\text{C}/\text{W}$  when mounted on a  $1\ \text{in}^2$  pad of 2 oz copper.



b.  $145\text{ }^\circ\text{C}/\text{W}$  when mounted on a minimum pad of 2 oz copper.

2. Pulse Test: Pulse Width <  $300\ \mu\text{s}$ , Duty cycle < 2.0%.

3. Pulsed  $I_d$  limited by junction temperature,  $t_d \leq 10\ \mu\text{s}$ , please refer to SOA curve for more details.

**Typical Characteristics**  $T_J = 25^\circ\text{C}$  unless otherwise noted

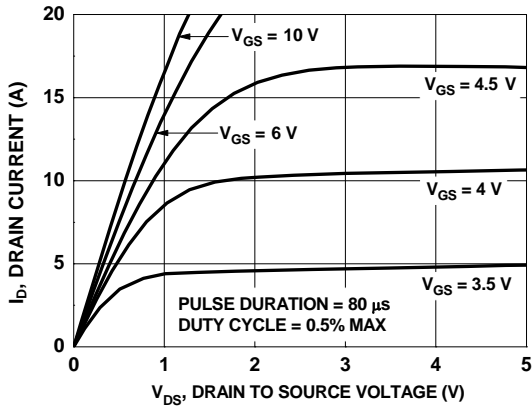


Figure 1. On-Region Characteristics

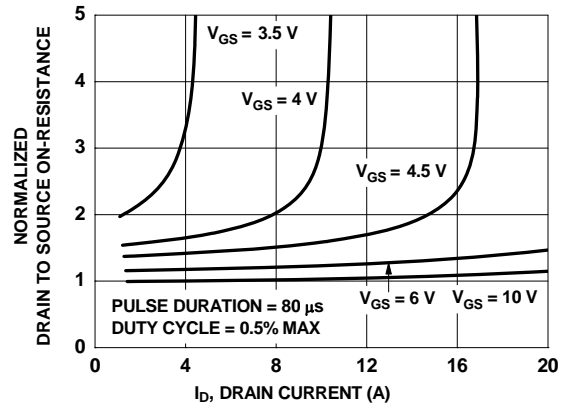


Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage

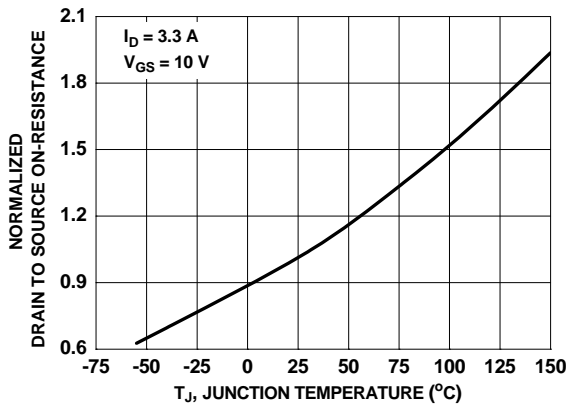


Figure 3. Normalized On-Resistance vs Junction Temperature

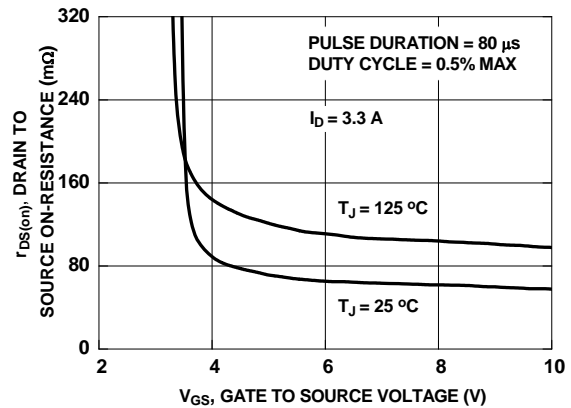


Figure 4. On-Resistance vs Gate to Source Voltage

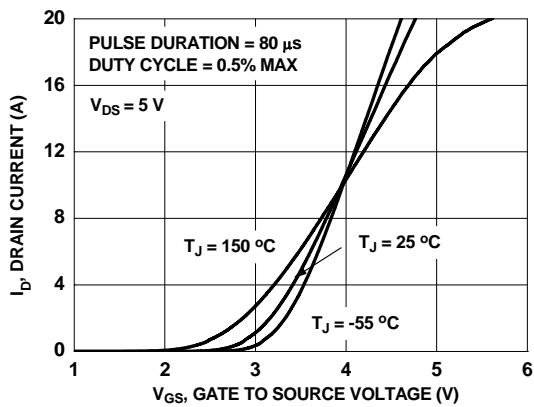


Figure 5. Transfer Characteristics

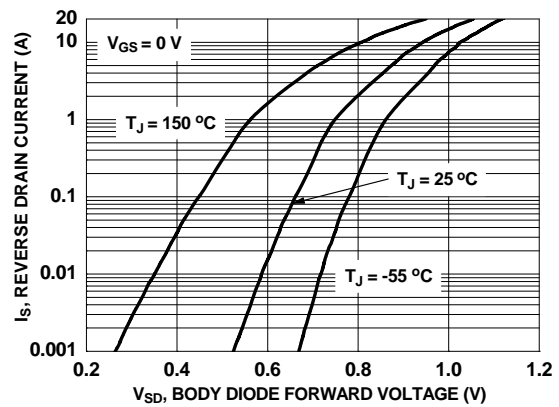
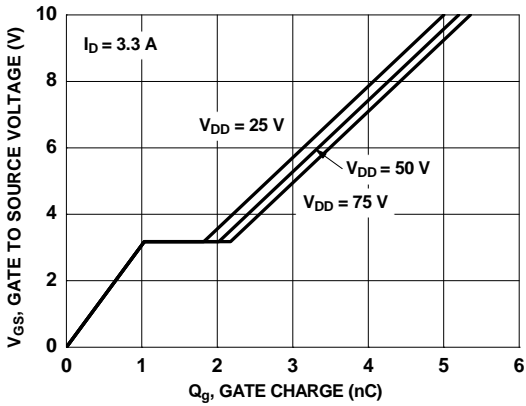
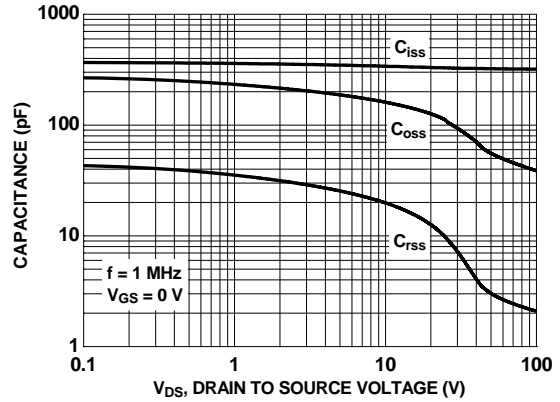


Figure 6. Source to Drain Diode Forward Voltage vs Source Current

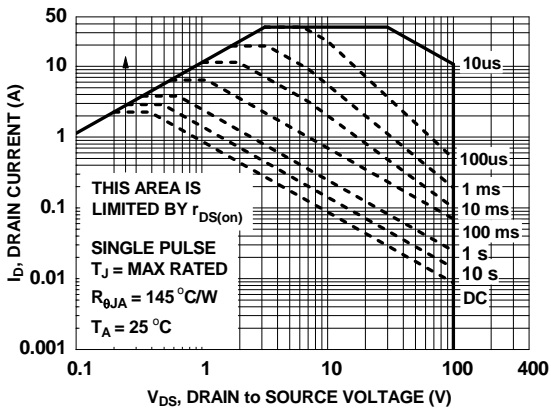
**Typical Characteristics**  $T_J = 25^\circ\text{C}$  unless otherwise noted



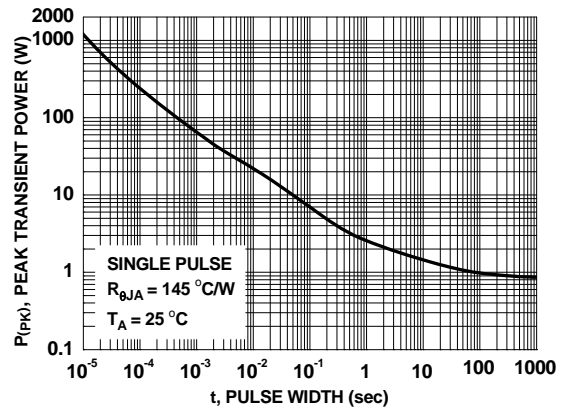
**Figure 7. Gate Charge Characteristics**



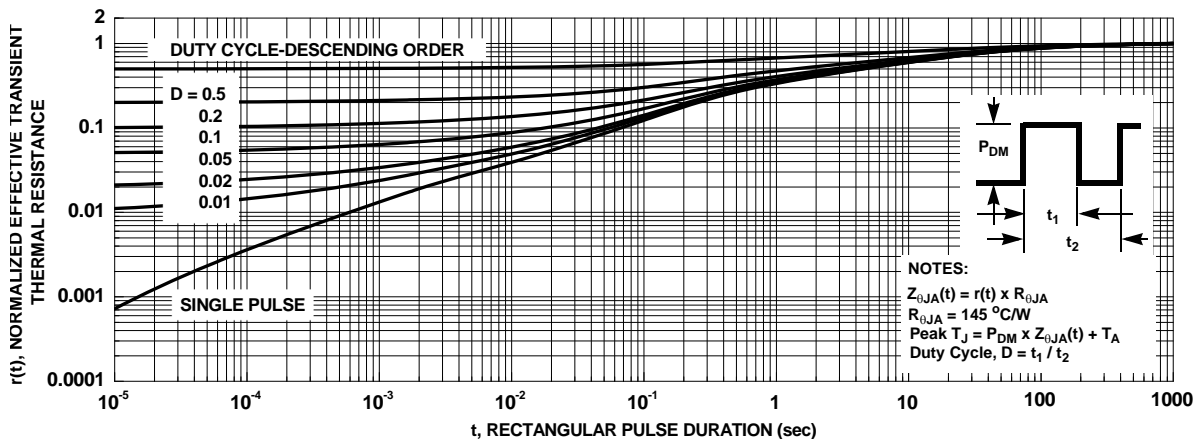
**Figure 8. Capacitance vs Drain to Source Voltage**



**Figure 9. Forward Bias Safe Operating Area**

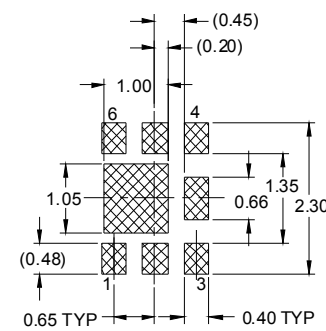
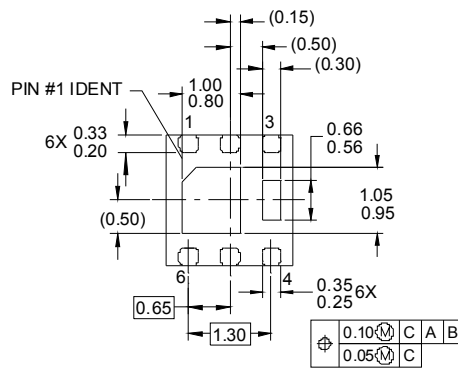
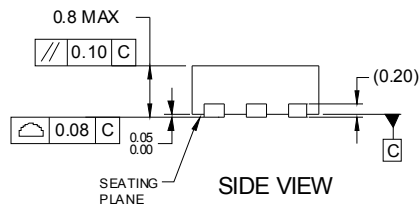
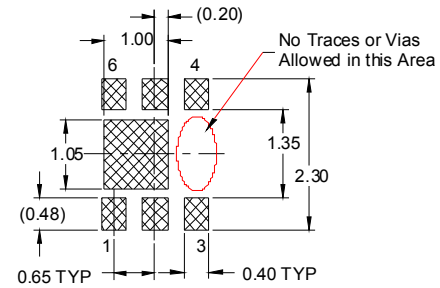
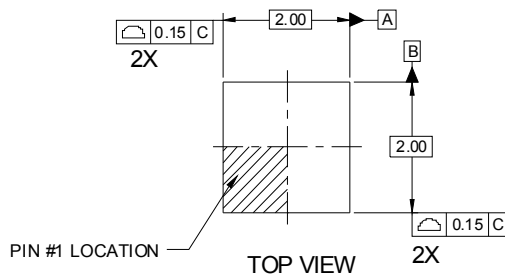


**Figure 10. Single Pulse Maximum Power Dissipation**



**Figure 11. Single Pulse Junction-to-Ambient Transient Thermal Response Curve**

## Dimensional Outline and Pad Layout



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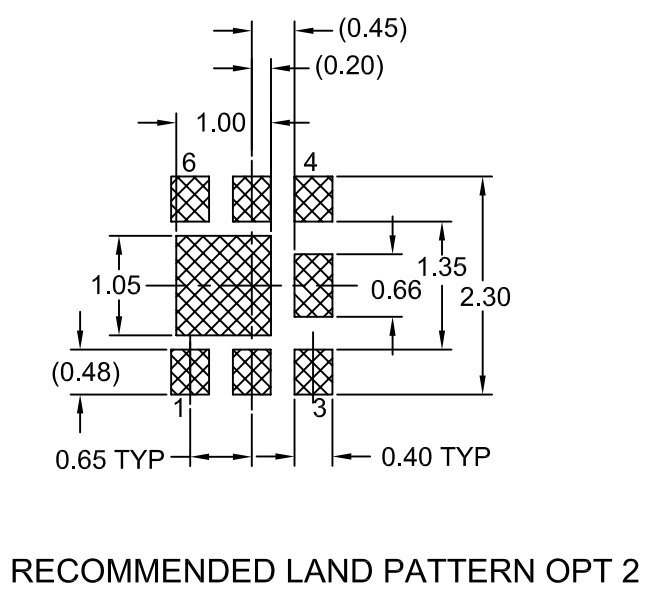
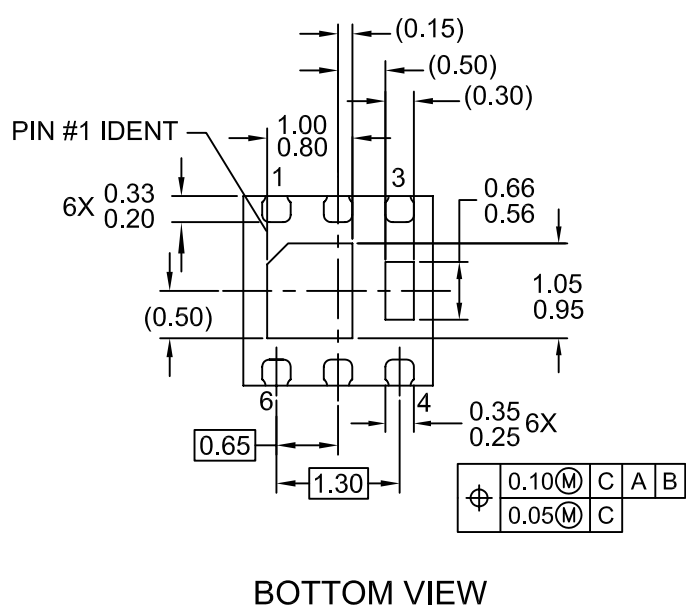
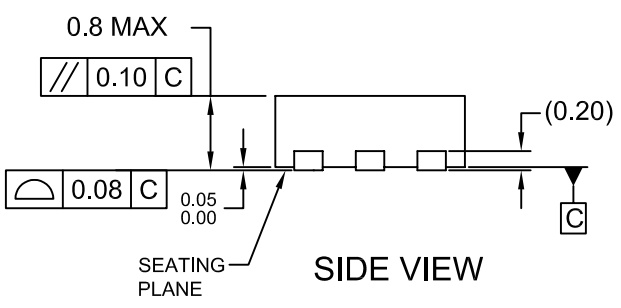
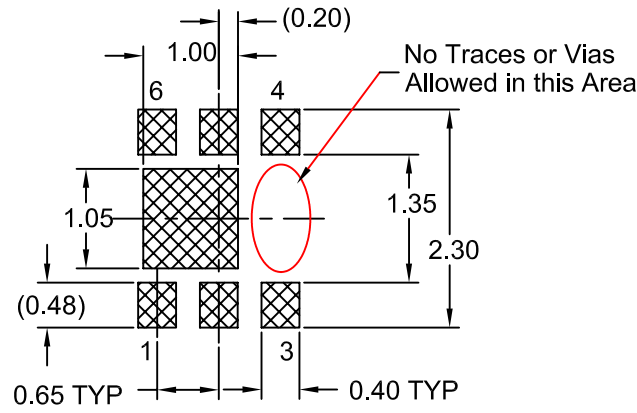
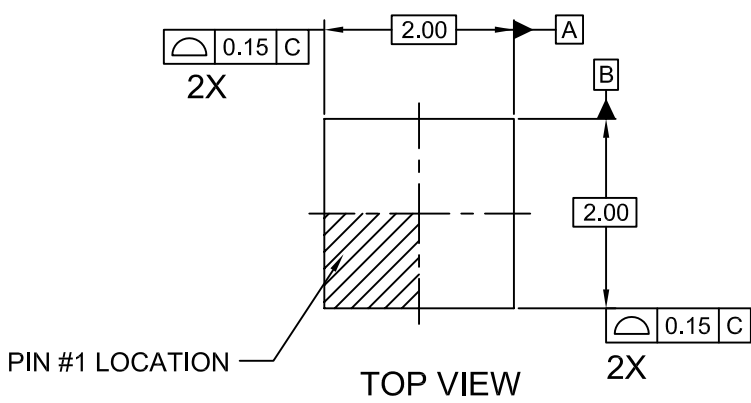
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